**Product data sheet** 

## 1. Product profile

### 1.1 General description

Single high-speed switching diode, encapsulated in a SOD323F (SC-90) very small and flat lead Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features

- High switching speed:  $t_{rr} \le 50$  ns
- Low leakage current
- Repetitive peak reverse voltage: V<sub>RRM</sub> ≤ 300 V
- Excellent coplanarity and improved thermal behavior
- Low capacitance: C<sub>d</sub> ≤ 2 pF
- Reverse voltage: V<sub>R</sub> ≤ 300 V
- Very small and flat lead SMD plastic package

### 1.3 Applications

- High-speed switching
- General-purpose switching
- Voltage clamping
- Reverse polarity protection

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current		<u>[1]</u> -	-	250	mA
I <sub>R</sub>	reverse current	$V_{R} = 250 \text{ V}$	-	-	150	nA
$V_R$	reverse voltage		-	-	300	V
t <sub>rr</sub>	reverse recovery time		[2] _	-	50	ns

<sup>[1]</sup> Pulse test:  $t_0 \le 300 \,\mu\text{s}$ ;  $\delta \le 0.02$ .



<sup>[2]</sup> When switched from  $I_F$  = 30 mA to  $I_R$  = 30 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 3 mA.

### Single high-speed switching diode

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	1.4
2	anode	1 2	+
			sym006

<sup>[1]</sup> The marking bar indicates the cathode.

# 3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BAS21J	SC-90	plastic surface-mounted package; 2 leads	SOD323F	

# 4. Marking

Table 4. Marking codes

Type number	Marking code
BAS21J	AN

#### Single high-speed switching diode

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	,		
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	300	V
$V_R$	reverse voltage		-	300	V
I <sub>F</sub>	forward current		<u>[1]</u> _	250	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 0.5 \text{ ms}; \\ \delta \leq 0.25$	-	1	Α
I <sub>FSM</sub>	non-repetitive peak forward current	square wave	[2]		
		$t_p = 100 \; \mu s$	-	3	Α
		$t_p = 1 \text{ ms}$	-	2.3	Α
		$t_p = 10 \text{ ms}$	-	1.7	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[3][4]	550	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	230	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3] -	-	55	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup>  $T_i = 25$  °C prior to surge.

<sup>[3]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>

<sup>[4]</sup> Reflow soldering is the only recommended soldering method.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Soldering point of cathode tab.

### Single high-speed switching diode

## 7. Characteristics

Table 7. Characteristics

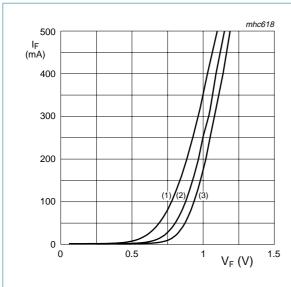
 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage	$I_F = 100 \text{ mA}$	<u>[1]</u> _	-	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 250 V	-	-	150	nA
		$V_R = 250 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
$C_d$	diode capacitance	$V_R = 0 V$ ; $f = 1 MHz$	-	-	2	pF
t <sub>rr</sub>	reverse recovery time		[2] _	-	50	ns

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

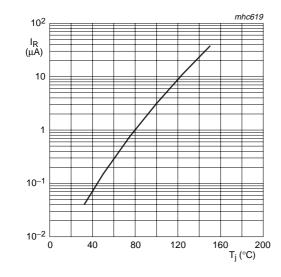
<sup>[2]</sup> When switched from I<sub>F</sub> = 30 mA to I<sub>R</sub> = 30 mA; R<sub>L</sub> = 100  $\Omega$ ; measured at I<sub>R</sub> = 3 mA.

### Single high-speed switching diode



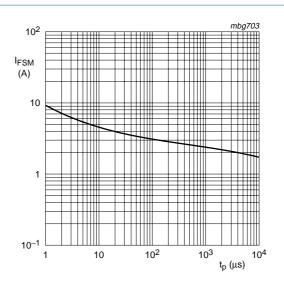
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 75 \,^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



 $V_{R} = 250 \text{ V}$ 

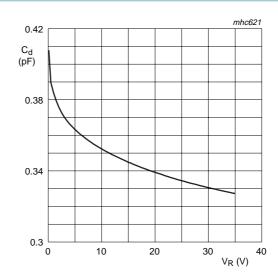
Fig 3. Reverse current as a function of junction temperature; typical values



Based on square wave currents.

 $T_i = 25$  °C; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



 $f = 1 \text{ MHz}; T_{amb} = 25 \, ^{\circ}\text{C}$ 

Fig 4. Diode capacitance as a function of reverse voltage; typical values

### Single high-speed switching diode

## 8. Test information

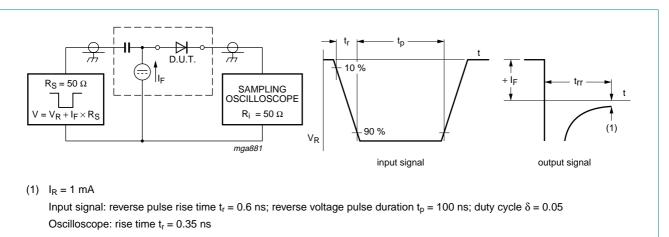
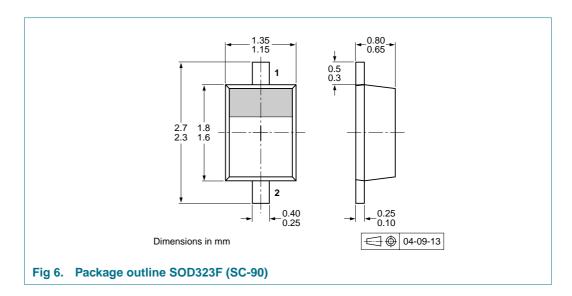


Fig 5. Reverse recovery time test circuit and waveforms

#### Single high-speed switching diode

## 9. Package outline



# 10. Packing information

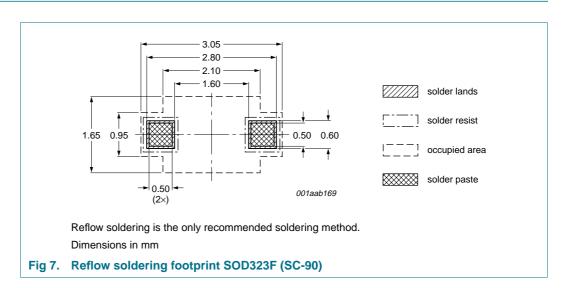
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing qu	antity
			3000	10000
BAS21J	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

# 11. Soldering



## Single high-speed switching diode

# 12. Revision history

### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS21J_1	20070308	Product data sheet	-	-

#### Single high-speed switching diode

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### Single high-speed switching diode

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